

NTMD6601NR2G Information


For Reference Only

Part Number [NTMD6601NR2G](#)
Manufacturer ON Semiconductor
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Arrays](#)
Description MOSFET 2N-CH 80V 1.1A 8SOIC
Package 8-SOIC (0.154", 3.90mm Width)
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


NTMD6601NR2G Specifications

Manufacturer Part Number	NTMD6601NR2G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	-
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (V _{dss})	80V
Current - Continuous Drain (I _d) @ 25°C	1.1A
R _{ds} On (Max) @ I _d , V _{gs}	215 mOhm @ 2.2A, 10V
V _{gs} (th) (Max) @ I _d	3V @ 250μA
Gate Charge (Q _g) (Max) @ V _{gs}	15nC @ 10V
Input Capacitance (C _{iss}) (Max) @ V _{ds}	400pF @ 25V
Power - Max	600mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SOIC

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NTMD6601NR2G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NTMD6601NR2G Payment Methods



NTMD6601NR2G Shipping Methods



If you have any question about NTMD6601NR2G, please do not hesitate to contact us!

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